Monolithic Digital IC



LB11817

# **Three-Phase Full-Wave Linear Drive**

## Preliminary

### **Overview**

The LB11817 is a spindle motor driver for use in slimshaped FDDs that use 5 V power supply.

## **Functions and Features**

- Three-phase full-wave linear drive
- Low saturation voltage
- Built-in digital speed control
- Start/stop circuit (active low)
- · Speed switching
- Current limiter
- Index processing circuit
- The index timing can be adjustment with a variable resistor.
- Thermal protection circuit

# **Package Dimensions**

unit: mm

#### 3247-SSOP36



## **Specifications**

#### Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>CC</sub> max		7.0	V
Maximum output current	I <sub>O max</sub> 1	t ≤ 0.5 s	1.5	A
Maximum steady-state output current	I <sub>O max</sub> 2		1.0	A
Allowable power dissipation 1	Pdmax1	Independent IC	0.6	W
Operating temperature	Topr		-20 to +80	°C
Storage temperature	Tstg		-40 to +150	°C

#### Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V <sub>CC</sub>		4.2 to 6.5	V

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# Electrical Characteristics at Ta = 25°C, $V_{CC}$ = 5 V

Parameter	Symbol Conditions		Ratings			Note	
	Cyrnoor	Conditions	min	typ	max	max Unit	
Current drain	Icco	S/S = 5 V (standby mode)			10	μΑ	
	I <sub>CC</sub>	S/S = 0 V (normal operation)		17	25	mA	
SL bias current	I <sub>SL</sub>	$V_{SL} = 0 V$			10	μA	
SL low-level input voltage	V <sub>SLL</sub>		0		1.0	V	
SL high-level input voltage	V <sub>SLH</sub>		3.5		V <sub>CC</sub>	V	
S/S bias current	I <sub>S/S</sub>			150	230	μA	
S/S low voltage	V <sub>S/SL</sub>		0		0.8	V	
S/S high voltage	V <sub>S/SH</sub>		3.5		V <sub>CC</sub>	V	
Hall amplifier input bias current	Ι <sub>Η</sub>				10	μA	
Common-mode input voltage range	V <sub>h</sub>		1.5		V <sub>CC</sub> – 1.0	V	
Differential input voltage range	V <sub>dif</sub>		50		200	mVp-p	
Hall bias output voltage	V <sub>HB</sub>	I <sub>H</sub> = 5 mA	0.5	0.8	1.1	V	
Hall bias leakage current	I <sub>HBL</sub>	S/S = 5 V			±10	μA	
Output saturation voltage	Vsat	I <sub>O</sub> = 0.5 A sink+source		0.45	0.67	V	
Output leakage current	IOL				1.0	mA	
Current limiter	V <sub>lim</sub>		0.27	0.3	0.33	V	
Control amplifier voltage gain	G <sub>C</sub>		-9	-7	-5	dB	
Voltage gain inter-phase difference	$\Delta G_{C}$				±1	dB	
V/I conversion source current	+		9	14	19	μA	
V/I conversion sink current	I-		-9	-14	-19	μA	
V/I conversion current ratio	+/ -		0.8	1.0	1.2		
DSC buffer input current	IDSC				1.0	μA	
FG amplifier voltage gain	G <sub>FG</sub>			48		dB	*
FG offset amplifier input	V <sub>FG0</sub>				±10	mV	*
FG amplifier internal reference voltage	V <sub>FGB</sub>		2.2	2.5	2.8	V	
FG Schmitt hysteresis	∆Vsh			50		mV	*
Speed discriminator counts	N			1041.5			
Discriminator operating frequency	FD				1.1	MHz	*
Oscillator frequency range	Fosc				1.1	MHz	*
Index output low-level voltage	VIDL	I <sub>O</sub> = 2 mA			0.4	V	
Index output leakage current	I <sub>IDL</sub>				±10	μA	
Index amplifier common-mode input voltage range	V <sub>ID</sub>		1.0		V <sub>CC</sub> – 1.0	V	
Index input hysteresis	$\Delta V_{\text{ID}}$			25		mV	
Boost voltage	VP	Ip = -5 mA	1.39	1.55	1.71	V	
Thermal protection circuit operating temperature	TSD		150	180		°C	*
Hysteresis	ΔTSD			40		°C	*

Note: \* Items shown to be design target values are not measured.

### **Pin Assignment**





### **Truth Table**

	Source $\rightarrow$ sink	Hall input			
		U	V	W	
1	$V \to W$	Н	Н	L	
2	$V \ \rightarrow U$	L	Н	L	
3	$W \ \rightarrow U$	L	Н	Н	
4	$W \to V$	L	L	Н	
5	$U \ \rightarrow V$	Н	L	Н	
6	$U \to W$	Н	L	L	

### Index Delay Pulse Timing Chart



#### **Pin Functions**

Pin No.	Symbol	Pin voltage	Function	Equivalent circuit
1	тс		<ul> <li>Connection for the external capacitor used to adjust the index timing.</li> </ul>	
2	ID	L: 0.4 Vmax H: 4.5 Vmin	• Index output	
3	S/S	L: 1.0 Vmax H: 3.5 Vmin	• Start/stop control. This is an active-low input.	Vcc Vcc 3
4	SL	L: 1.0 Vmax H: 3.5 Vmin	• Speed switching input	Vcc Vcc 4
5	CLK	L: 0.5 Vmax H: V <sub>CC</sub> – 1.0 Vmin	<ul> <li>Reference clock input. The threshold voltage is 1.25 V. At 1 MHz, the LB11817 supports speeds of 300 and 360 rpm.</li> </ul>	Vcc
6	FC		<ul> <li>Frequency characteristics correction. Oscillation in the current control closed- loop circuit can be stopped by inserting a capacitor between this pin and ground.</li> </ul>	
7	DO		Speed discriminator	Image: Constraint of the second se

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Pin No.	Symbol	Pin voltage	Function	Equivalent circuit
8	GND		Ground     This pin and pin 34 must all be     connected to the frame ground.	
9	V <sub>CC</sub>	4.2 to 6.5 V	<ul> <li>Supply voltage This voltage must be stabilized so that ripple and noise do not enter the IC.</li> </ul>	
10	VP	V <sub>CC</sub> + 1.55 Vtyp (lp = -5 mA)	• Boosted voltage output Used as the output transistor pre-driver power supply. This boosted voltage is used when a low saturation output is provided. In all other cases this pin will be at the V <sub>CC</sub> potential.	
11	RF		• Output current detection An RF resistor inserted between this pin and $V_{CC}$ converts the output current to the voltage used for output current detection. The current limiter circuit operates by detecting the voltage on this pin.	
12 15	D2 D1		• Connections for the two diodes used by the voltage boost function.	12
13 14	B2 B1		• Boost function switching circuit outputs 1 and 2	$\begin{array}{c} & & & \\ & & & \\ & & & \\ \hline \hline & & & \\ \hline & & & \\ \hline & & & \\ \hline \hline \\ \hline & & & \\ \hline \hline \\ \hline & & & \\ \hline \hline \\ \hline \hline \\ \hline \\$
17 19 20	W <sub>OUT</sub> V <sub>OUT</sub> U <sub>OUT</sub>		<ul> <li>W-phase output</li> <li>V-phase output</li> <li>U-phase output</li> </ul>	

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Pin No.	Symbol	Pin voltage	Function	Equivalent circuit
18	PGND		Output transistor ground	
24 25 26 27 28 29	U <sub>IN</sub> + U <sub>IN</sub> - V <sub>IN</sub> + V <sub>IN</sub> - W <sub>IN</sub> + W <sub>IN</sub> -	1.5 Vmin V <sub>CC</sub> – 1.0 Vmax	<ul> <li>U-phase Hall device inputs</li> <li>V-phase Hall device inputs</li> <li>W-phase Hall device inputs</li> </ul>	$\begin{array}{c} \hline 24 \\ \hline 26 \\ \hline \\ 28 \\ \hline \\ \hline \\ 25 \\ \hline \\ 27 \\ \hline \\ 29 \\ \hline \\ \hline \\ \\ 29 \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $
30	НВ	0.8 Vtyp (IH = 5 mA)	<ul> <li>Negative potential that provides Hall device bias current In the stopped state, this pin is set to the open state to cut off the Hall device bias current.</li> </ul>	
31 32 33	FGO FG+ FG-	2.5 Vtyp	<ul> <li>FG amplifier output</li> <li>FG amplifier minus input</li> <li>FG amplifier plus input</li> <li>A 2.5 V reference voltage is generated internally by the IC.</li> </ul>	$\begin{array}{c} & & & \\ \hline \\ \hline$
34 35	+  _		• Index inputs	$\begin{array}{c} \begin{array}{c} \begin{array}{c} \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} \\ \end{array} \\ \end{array} \\ \begin{array}{c} \end{array} \\ \end{array} $
36	VR		Index timing adjustment voltage input	

#### **Block Diagram**

Note that the values of the external components shown here are reference values and are not guaranteed to be appropriate in a given application.



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